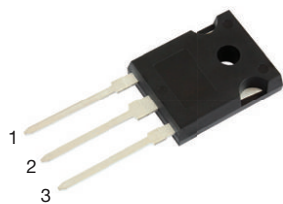
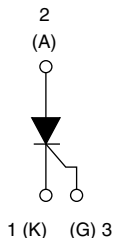


Thyristor High Voltage, Phase Control SCR, 100 A



TO-247AD 3L



FEATURES

- Designed and qualified according to JEDEC®-JESD 47
- 150 °C maximum operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-100TPS12L high voltage series of silicon controlled rectifiers are specifically designed for medium power switching, and phase control applications. The glass passivation technology used, has reliable operation up to 150 °C junction temperature.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS

$I_{T(AV)}$	100 A
V_{DRM}/V_{RRM}	1200 V
V_{TM} (typ.)	1.17 V
I_{GT}	100 mA
T_J	-40 °C to +150 °C
Package	TO-247AD 3L
Circuit configuration	Single SCR

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}/V_{DRM}		1200	V
On-state voltage	V_T	100 A, $T_J = 125$ °C, typical	1.17	
Average rectified forward current	$I_{T(AV)}$		100	A
Maximum continuous RMS on-state current	I_{RMS}		157	
Non-repetitive peak surge current	I_{TSM}	$T_J = 150$ °C, 10 ms sine	935	
Maximum rate of rise	dV/dt		1000	V/μs
Maximum operating junction and storage temperature range	T_J, T_{Stg}		-40 to +150	°C

VOLTAGE RATINGS

PART NUMBER	V_{RRM}/V_{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	TYP. I_{RRM}/I_{DRM} AT 150 °C mA
VS-100TPS12L-M3	1200	1300	28

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Maximum average on-state current	$I_{T(AV)}$	$T_C = 103\text{ }^{\circ}\text{C}$, 180° conduction half sine wave	-	100	A
Maximum continuous RMS on-state current as AC switch	$I_{T(RMS)}$		-	157	
Peak, one-cycle non-repetitive surge current	I_{TSM}	10 ms sine pulse, rated V_{RRM} applied	-	790	
I^2t for fusing	I^2t	10 ms sine pulse, no voltage reapplied	-	935	A^2s
		10 ms sine pulse, rated V_{RRM} applied	-	3090	
		10 ms sine pulse, no voltage reapplied	-	4370	
$I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$, no voltage reapplied, $T_J = 150\text{ }^{\circ}\text{C}$	-	43 700	$A^2\sqrt{s}$
On-state voltage	V_T	100 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.22	1.37	V
		190 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.45	1.61	
		100 A, $T_J = 125\text{ }^{\circ}\text{C}$	1.17	1.26	
		190 A, $T_J = 125\text{ }^{\circ}\text{C}$	1.47	1.60	
Low level value of threshold voltage	V_{T01}	$T_J = 150\text{ }^{\circ}\text{C}$	-	0.82	V
High level value of threshold voltage	V_{T02}		-	0.93	
Low level value of on-state slope resistance	r_{t1}	$T_J = 150\text{ }^{\circ}\text{C}$	-	3.80	$m\Omega$
High level value of on-state slope resistance	r_{t2}		-	3.50	
Rate of rise of turned-on current	di/dt	$T_J = 150\text{ }^{\circ}\text{C}$, $V_R < 800\text{ V}$, $I_T = 100\text{ A}$, $I_{gt} = 200\text{ mA}$, $t_r < 100\text{ ns}$, repetitive	-	200	$A/\mu s$
Rate of rise of turned-on current	di/dt	$T_J = 150\text{ }^{\circ}\text{C}$, $V_R < 1000\text{ V}$, $I_T = 100\text{ A}$, $I_{gt} = 200\text{ mA}$, $t_r < 100\text{ ns}$, non repetitive	-	500	$A/\mu s$
Holding current	I_H	Anode supply = 6 V, resistive load, $T_J = 25\text{ }^{\circ}\text{C}$	-	300	mA
Latching current	I_L		-	500	
Reverse and direct leakage current	I_{RRM}/I_{DRM}	$T_J = 25\text{ }^{\circ}\text{C}$	30	100	μA
		$T_J = 125\text{ }^{\circ}\text{C}$	10	50	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	28	70	
Rate of rise of off-state voltage	dV/dt	$T_J = T_J\text{ maximum}$, linear to 80 % V_{DRM} , $R_{g-k} = \text{open}$	-	1000	$V/\mu s$

TRIGGERING

PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Peak gate power	P_{GM}	10 ms sine pulse, no voltage reapplied	-	10	W
Average gate power	$P_{G(AV)}$		-	2.5	
Peak gate current	I_{GM}		-	2.5	A
Peak negative gate voltage	$-V_{GM}$		-	10	V
Required DC gate voltage to trigger	V_{GT}	$T_J = -40\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	1.2	1.7	
		$T_J = 25\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	1.0	1.5	
		$T_J = 125\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	0.7	1.3	
		$T_J = 150\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	0.6	1.1	
Required DC gate to trigger	I_{GT}	$T_J = -40\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	80	150	mA
		$T_J = 25\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	60	100	
		$T_J = 125\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	25	50	
		$T_J = 150\text{ }^{\circ}\text{C}$ Anode supply = 6 V resistive load	17	35	
DC gate voltage not to trigger	V_{GD}	$T_J = 150\text{ }^{\circ}\text{C}$, $V_{DRM} = 80\text{ } \%$ rated value	-	0.20	V
DC gate current not to trigger	I_{GD}		-	3.0	mA

SWITCHING

PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Turn-on time	t_{gt}	$I_T = 100\text{ A}$, $V_D = 50\text{ } \%$ V_{DRM} , $I_{gt} = 300\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.8	-	μs
Turn-off time	t_q	$I_T = 100\text{ A}$, $V_D = 80\text{ } \%$ V_{DRM} , $dV/dt = 20\text{ V}/\mu s$, $t_p = 200\text{ }\mu s$, $I_{gt} = 100\text{ mA}$, $di/dt = 10\text{ A}/\mu s$, $V_R = 100\text{ V}$, $T_J = 150\text{ }^{\circ}\text{C}$	135	-	



ΔR_{thJ-HS} CONDUCTION PER JUNCTION

DEVICE	SINE HALF-WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VS-100TPS12L-M3	0.032	0.047	0.042	0.044	0.046	0.030	0.039	0.041	0.044	0.046	°C/W

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	MAX.	UNITS
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-40	150	°C
Maximum thermal resistance, junction to case	R _{thJC}		-	0.25	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		-	40	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.20		
Approximate weight			6		g
Mounting torque	minimum		6 (5)		kgf · cm (lbf · in)
	maximum		12 (10)		
Marking device		Case style TO-247AD 3L	100TPS12L		

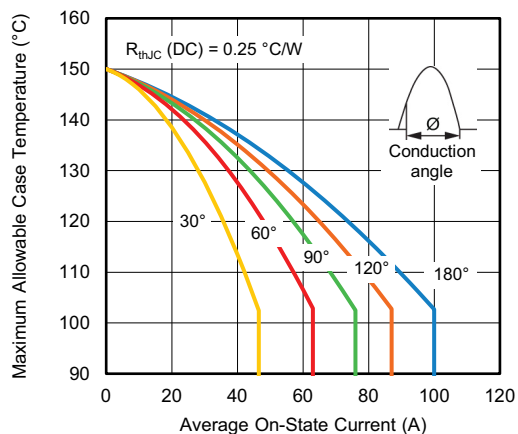


Fig. 1 - Current Rating Characteristics

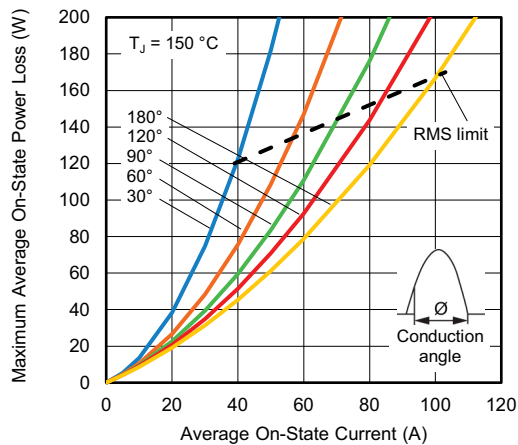


Fig. 3 - On-State Power Loss Characteristics

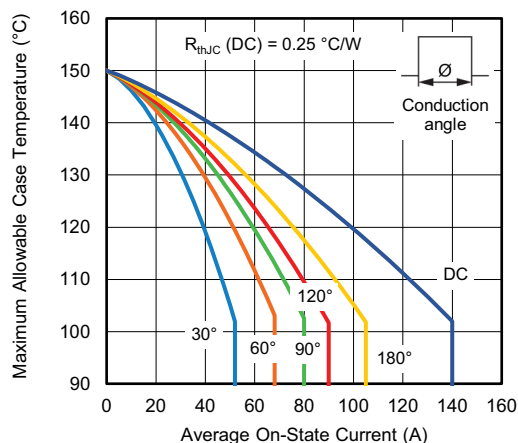


Fig. 2 - Current Rating Characteristics

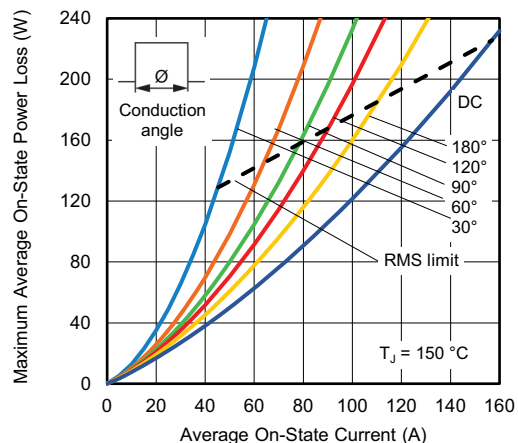


Fig. 4 - On-State Power Loss Characteristic

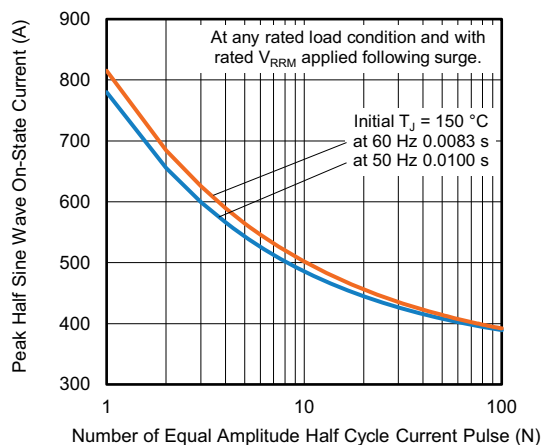


Fig. 5 - Maximum Non-Repetitive Surge Current

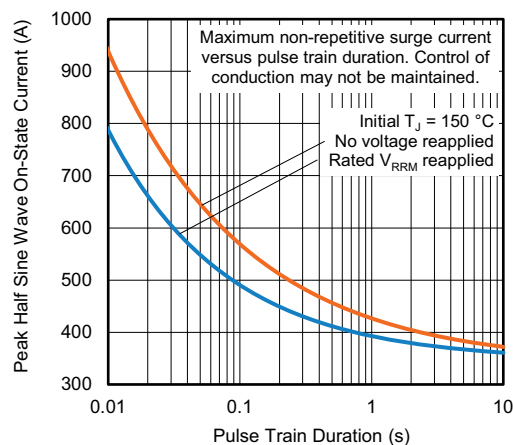


Fig. 6 - Maximum Non-Repetitive Surge Current

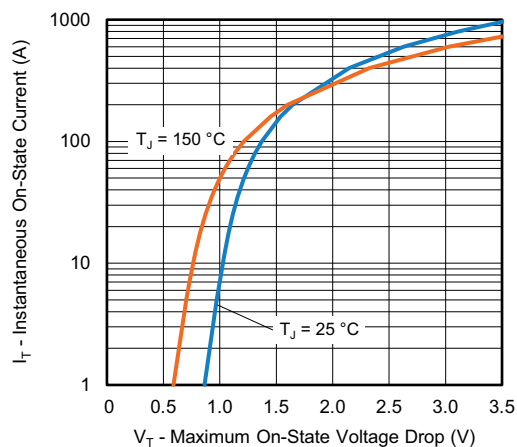
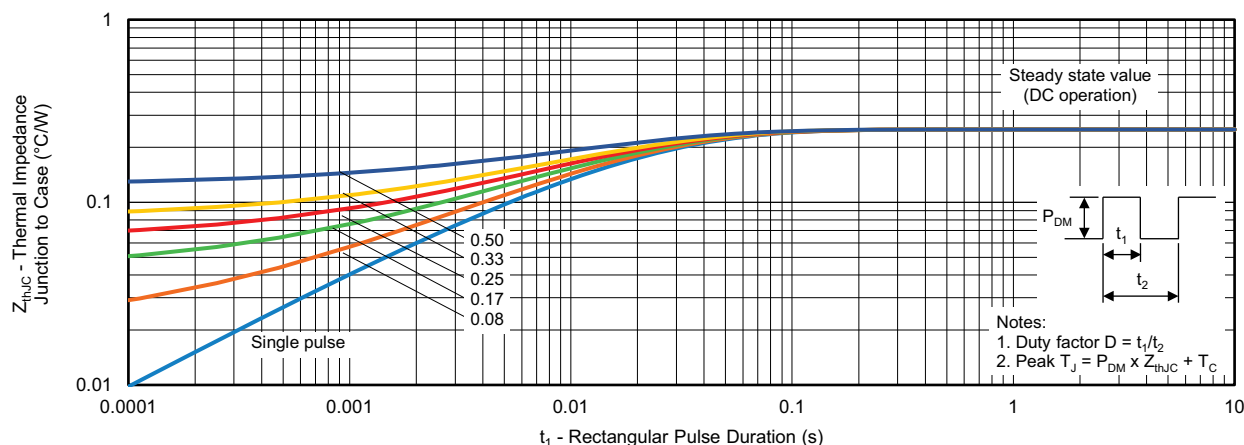


Fig. 7 - On-State Voltage Drop Characteristics


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

**ORDERING INFORMATION TABLE**

Device code	VS-	100	T	P	S	12	L	-M3
	1	2	3	4	5	6	7	8

- | | | |
|----------|---|---|
| 1 | - | Vishay Semiconductors product |
| 2 | - | Current code (100 = 100 A) |
| 3 | - | Circuit configuration:
T = thyristor |
| 4 | - | P = TO-247 package |
| 5 | - | Type of silicon:
S = standard recovery rectifier |
| 6 | - | Voltage code (12 = 1200 V) |
| 7 | - | Package L = long lead |
| 8 | - | -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free |

ORDERING INFORMATION (example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-100TPS12L-M3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95626
Part marking information	www.vishay.com/doc?95007

TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
ϕK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ϕP	3.56	3.66	0.14	0.144	
$\phi P1$	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Contour of slot optional
- Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- ϕP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.